DATA SHEET



MOS FIELD EFFECT TRANSISTOR

NP88N055CLE,NP88N055DLE,NP88N055ELE,NP88N055KLE

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

These products are N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance
- $\begin{array}{l} {\sf R}_{\sf DS(on)1}=5.2\ m\Omega \ \ {\sf MAX}.\ ({\sf V}_{\sf GS}=10\ {\sf V},\ {\sf I}_{\sf D}=44\ {\sf A}) \\ {\sf R}_{\sf DS(on)2}=6.3\ m\Omega \ \ {\sf MAX}.\ ({\sf V}_{\sf GS}=5.0\ {\sf V},\ {\sf I}_{\sf D}=44\ {\sf A}) \end{array}$
- Low Ciss: Ciss = 9700 pF TYP.
- Built-in gate protection diode

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	55	V
Gate to Source Voltage ($V_{DS} = 0 V$)	Vgss	±20	V
Drain Current (DC) Note1	ID(DC)	±88	А
Drain Current (pulse) Note2	D(pulse)	±352	А
Total Power Dissipation ($T_A = 25^{\circ}C$)	P⊤	1.8	W
Total Power Dissipation ($Tc = 25^{\circ}C$)	Pτ	288	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	-55 to +175	°C
Single Avalanche Current Note3	las	75/88	А
Single Avalanche Energy Note3	Eas	562/232	mJ

Notes 1. Calculated constant current according to MAX. allowable channel temperature.

- **2.** PW \leq 10 μ s, Duty cycle \leq 1%
- 3. Starting T_ch = 25°C, R_G = 25 Ω , V_Gs = 20 \rightarrow 0 V (see Figure 4.)

THERMAL RESISTANCE

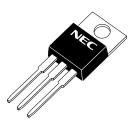
Channel to Case Thermal Resistance	$R_{th(ch-C)}$	0.52	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

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ORDERING INFORMATION

	PART NUMBER	PACKAGE		
	NP88N055CLE	TO-220AB		
	NP88N055DLE TO-262			
	NP88N055ELE	TO-263 (MP-25ZJ)		
★	NP88N055KLE	TO-263 (MP-25ZK)		

(TO-220AB)



(TO-262)



(TO-263)

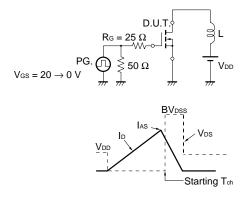


The mark \star shows major revised points.

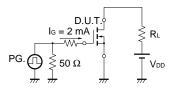
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	Vds = 55 V, Vgs = 0 V			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate to Source Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	1.5	2.0	2.5	V
Forward Transfer Admittance	y _{fs}	Vds = 10 V, Id = 44 A	38	75		S
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 44 A		4.1	5.2	mΩ
	RDS(on)2	Vgs = 5.0 V, Id = 44 A		4.8	6.3	mΩ
	RDS(on)3	Vgs = 4.5 V, Id = 44 A		5.1	6.8	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V		9700	14600	pF
Output Capacitance	Coss	Vgs = 0 V		1100	1700	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		490	890	pF
Turn-on Delay Time	td(on)	$V_{DD} = 28 V, I_D = 44 A$		37	82	ns
Rise Time	tr	Vgs = 10 V		22	56	ns
Turn-off Delay Time	td(off)	Rg = 1 Ω		180	360	ns
Fall Time	tr			35	88	ns
Total Gate Charge 1	Q _{G1}	$V_{DD} = 44 V$, $V_{GS} = 10 V$, $I_D = 88 A$		160	240	nC
Total Gate Charge 2	Q _{G2}	Vdd = 44 V		88	140	nC
Gate to Source Charge	Q _{GS}	Vgs = 5.0 V		27		nC
Gate to Drain Charge	Qgd	ID = 88 A		48		nC
Body Diode Forward Voltage	VF(S-D)	IF = 88 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 88 A, VGS = 0 V		62		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		120		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

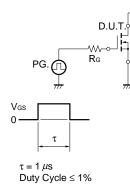


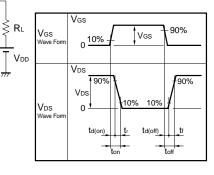
TEST CIRCUIT 3 GATE CHARGE



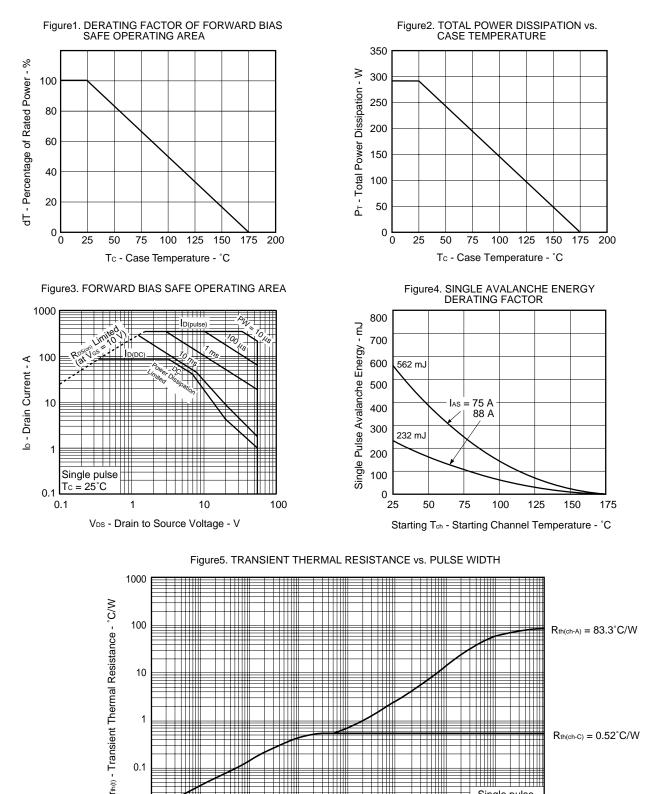
TEST CIRCUIT 2 SWITCHING TIME

₩





TYPICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)



100 m

PW - Pulse Width - s

1 m

10 m

 $100 \, \mu$

0.01

10*µ*

1

Ш

10

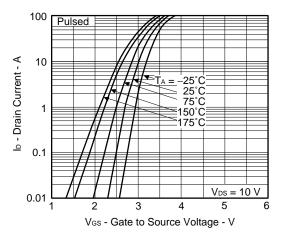
Single pulse

1000

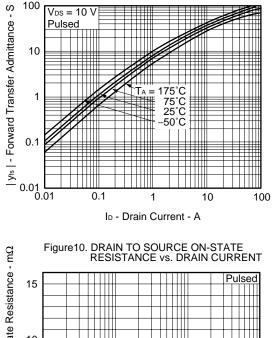
Tc = 25°C

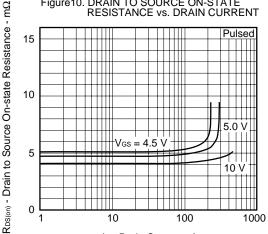
100

Figure6. FORWARD TRANSFER CHARACTERISTICS

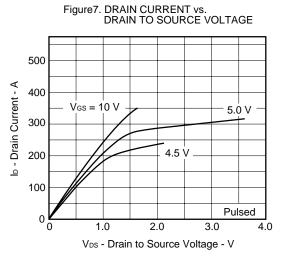








ID - Drain Current - A



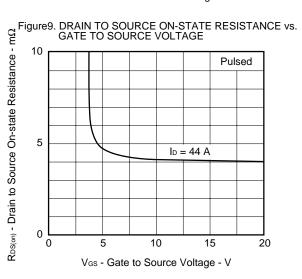
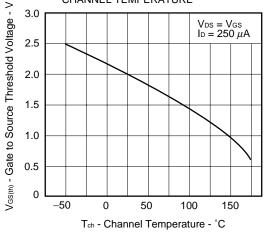
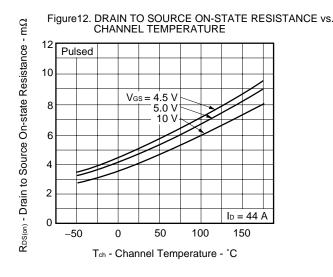


Figure11. GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE





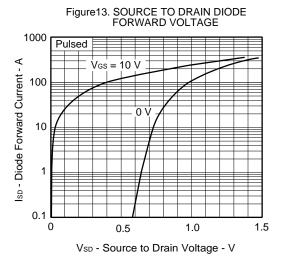
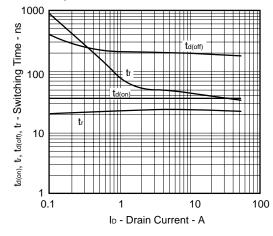
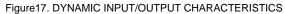
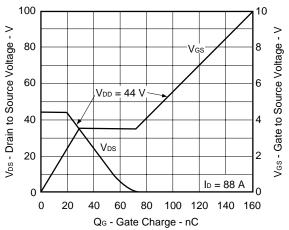
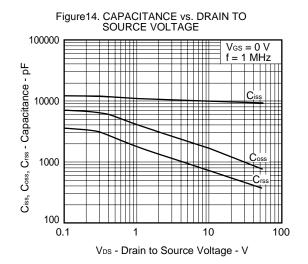


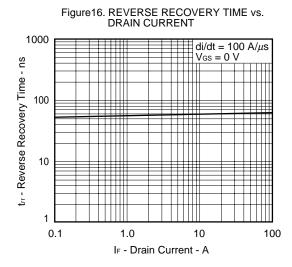
Figure15. SWITCHING CHARACTERISTICS











PACKAGE DRAWINGS (Unit: mm)

1) TO-220AB (MP-25)

3) TO-263 (MP-25ZJ)

1.0±0.5

<u>1.4±0.2</u>

0.7±0.2

2.54 TYP

10 TYP.

2 3

 \Box

Δ

8.5±0.2

5.7±0.4

2.54 TYP.

2.8±0.2

0.5RTVP.

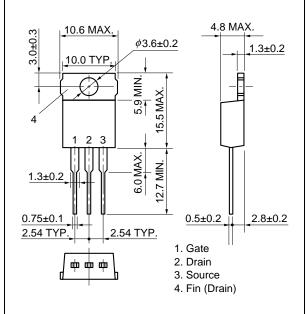
0.8RTYP.

1. Gate

2. Drain

3. Source

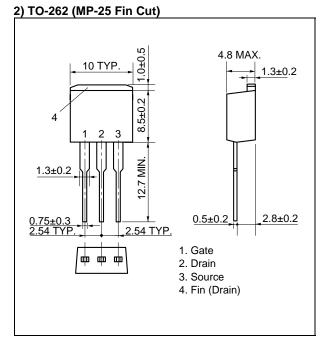
4. Fin (Drain)



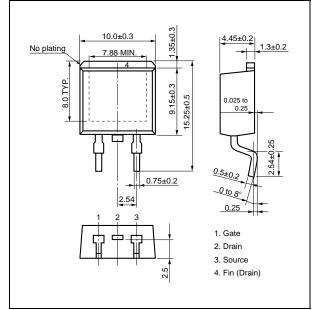
4.8 MAX.

1.3±0.2

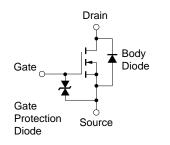
0.5±0.2



★ 4) TO-263 (MP-25ZK)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

[MEMO]

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